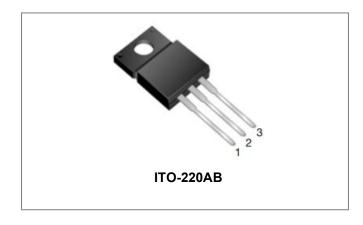


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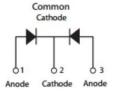
MBRF2080CTL SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	80	V
Average Rectified Forward Current	I _{F (AV)}	Tc=120°C, In DC	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	A

Electrical Characteristics:

Characteristics	Symbol	Condition		Min.	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@10A, Pulse, TJ	@10A, Pulse, T _J = 25 °C		0.71	0.75	V
	V _{F2}	@ 10A, Pulse, T _J :	@ 10A, Pulse, T _J = 125 °C		0.63	0.70	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T,	@V _R = rated V _R , T _J = 25 °C		0.07	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C		-	25	50	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$		-	300	500	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body		-	8.0	-	nH
Voltage Rate of Change	dv/dt	-		-	-	10,000	V/μs
Isolation Voltage	V _{ISO}	t = 1.0 second	50/60HZ, RMS;	3000	-	-	V
		t = 1.0 minute	I _{ISO} ≤1mA	2500	-	-	

^{*} Pulse width < 300 µs, duty cycle < 2%

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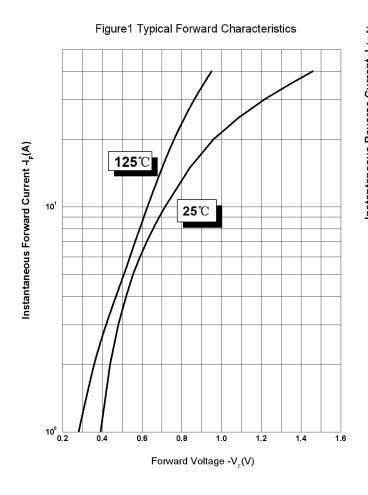




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	DC operation	4	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



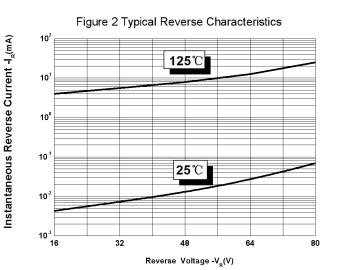


Figure 3 Typical Junction Capacitance

10000
1000
2 4 6 8 10

Reverse Voltage -V_p(V)

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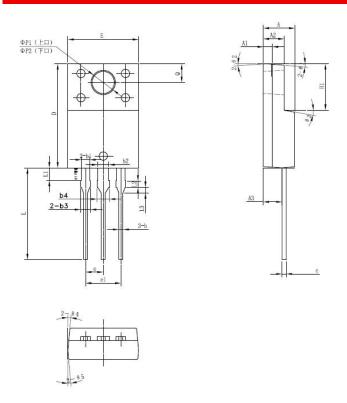


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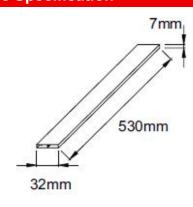


Mechanical Dimensions ITO-220AB



OVMBOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10 1.30		1.50		
A2	2.80 3.00		3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
<u>E</u>	9.96 10.16		10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70 13.20		13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦP1(上□)	3.30	3.50	3.70		
ΦP2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

 MBR
 = Device Type

 F
 = Package type

 20
 = Forward Current (20A)

 80
 = Reverse Voltage (80V)

 CTL
 = Configuration

 SSG
 = SSG

 YY
 = Year

WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
MBRF2080CTL	ITO-220AB	50 peo/tube
	(Pb-Free)	50 pcs/ tube

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MBRF2080CTL



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